Product data sheet

1. General description

Dual common cathode power Schottky diode in TO252 (DPAK) plastic package.





2. Features and benefits

- Trench structure
- High junction temperature up to 150°C
- Low forward voltage drop
- · Negligible switching losses
- High efficiency

3. Applications

- DC to DC converters
- Freewheeling diode
- OR-ing diode
- · Switched mode power supply rectifier

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Notes	s Values			Unit
Absolute	maximum rating						
V_{RRM}	repetitive peak reverse voltage				V		
$I_{F(AV)}$	average forward current	δ = 0.5 ; square-wave pulse; T _{mb} ≤ 136 °C; per diode; Fig. 1; Fig. 2; Fig. 3		5			Α
I _{O(AV)}	average output current	δ = 0.5 ; square-wave pulse; $T_{mb} \le$ 132 °C; both diodes conducting		10			Α
Symbol	Parameter	Conditions	Notes	s Min Typ Max			Unit
Static ch	aracteristics						
V _F	forward voltage	I _F = 5 A; T _j = 25 °C; per diode; <u>Fig. 6</u>		-	0.63	0.69	V
		I _F = 5 A; T _j = 125 °C; per diode; <u>Fig. 6</u>		-	0.61	0.65	V
I _R	reverse current	reverse current $V_R = 65 \text{ V}; T_j = 25 \text{ °C}; \text{ per diode}; $ Fig. 7; Fig. 8		-	7	70	μA
		$V_R = 65 \text{ V}; T_j = 125 \text{ °C}; \text{ per diode}; Fig. 7; Fig. 8$		-	3	15	mA

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	A1	anode 1		
2	K	cathode		A1
3	A2	anode 2		K
mb	К	mounting base; connected to cathode		sym125

6. Ordering information

Table 3. Ordering information

Type number	Package name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date
WN3S10H65CD	TO252	WN3S10H65CDJ	Reel	2500	TO252d	07-Sep-2022

7. Marking

Table 4. Marking codes

Type number	Marking codes
WN3S10H65CD	WN3S10H 65CD

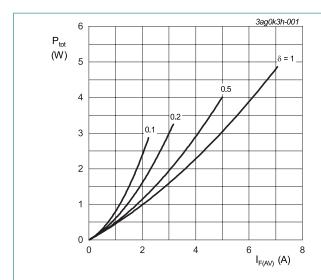
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

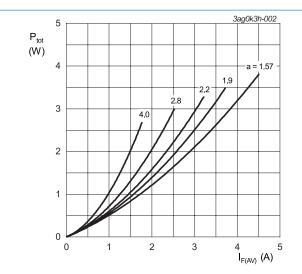
Symbol	Parameter	Conditions	Notes	Values	Unit
V_{RRM}	repetitive peak reverse voltage			65	V
V_{RWM}	crest working reverse voltage			65	V
V_R	reverse voltage	DC		65	V
I _{F(AV)}	average forward current	$δ$ = 0.5; square-wave pulse; $T_{mb} \le 136$ °C; per diode; Fig. 1; Fig. 2; Fig. 3		5	А
$I_{O(AV)}$	average output current	δ = 0.5; square-wave pulse; $T_{mb} \le 132$ °C; both diodes conducting		10	А
I _{FSM}	non-repetitive peak forward current	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 4		45	А
		t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse		50	Α
T _{stg}	storage temperature			-40 to 150	°C
T _j	junction temperature		[1]	-40 to 150	°C

[1] The heat generated must be less than the thermal conductivity from junction to ambient: $dP_{tot}/dT_j < 1/R_{th(j-a)}$



 $\begin{aligned} &I_{\text{F(AV)}} = I_{\text{F(RMS)}} \times \sqrt{\delta} \\ &V_{\text{o}} = 0.414 \text{ V; } R_{\text{s}} = 0.0388 \text{ } \Omega \end{aligned}$

Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values; per diode



a = form factor = $I_{F(RMS)}/I_{F(AV)}$ V_o = 0.414 V; R_s = 0.0388 Ω

Fig. 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values; per diode

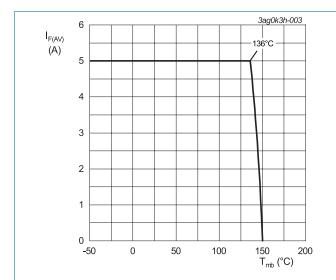


Fig. 3. Average forward current as a function of mounting base temperature; maximum values; per diode

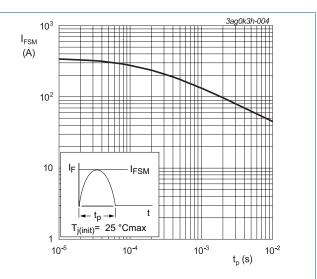


Fig. 4. Non-repetitive peak forward current as a function of pulse width; sinusoidal waveform; maximum values; per diode

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit
$R_{\text{th(j-mb)}}$	thermal resistance from junction to	per diode; Fig. 5		-	-	3.5	K/W
	mounting base	both diodes conducting		-	-	2.2	K/W
R _{th(j-a)}	thermal resistance from junction to ambient free air	in free air		-	75	-	K/W

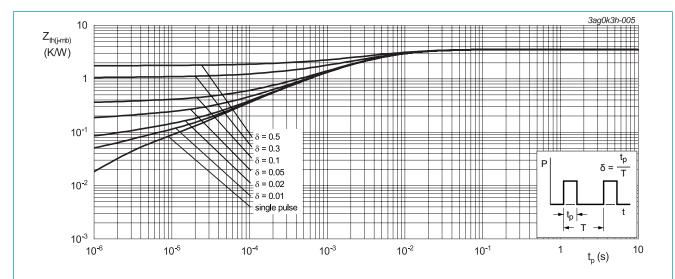
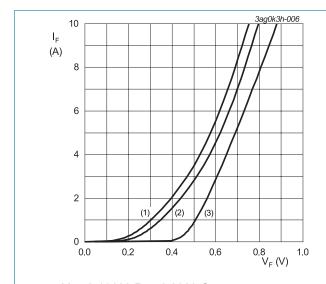


Fig. 5. Transient thermal impedance from junction to mounting base as a function of pulse duration; maximum values; per diode

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Notes	Min	Тур	Max	Unit	
Static characteristics								
V_{F}	forward voltage	$I_F = 5 \text{ A}; T_j = 25 \text{ °C}; \text{ per diode}; Fig. 6$		-	0.63	0.69	V	
		I _F = 5 A; T _j = 125 °C; per diode; <u>Fig. 6</u>		-	0.61	0.65	V	
I _R	reverse current	$V_R = 60 \text{ V; } T_j = 25 \text{ °C; per diode;}$ Fig. 7; Fig. 8		-	5	40	μA	
		$V_R = 65 \text{ V; } T_j = 25 \text{ °C; per diode;}$ Fig. 7; Fig. 8		-	7	70	μA	
		$V_R = 65 \text{ V}; T_j = 125 \text{ °C}; \text{ per diode}; $ Fig. 7; Fig. 8		-	3	15	mA	

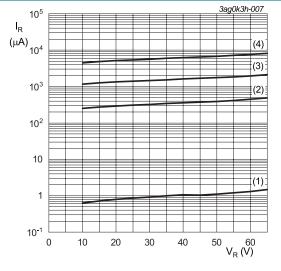


 V_o = 0.414 V; R_s = 0.0388 Ω

(1) T_j = 150 °C; typical values (2) T_j = 150 °C; maximum values

(3) T_i = 25 °C; maximum values

Forward current as a function of forward voltage; per diode

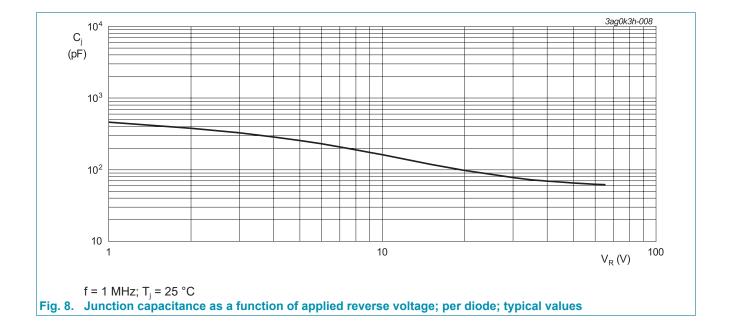


(1) T_i = 25 °C; typical values

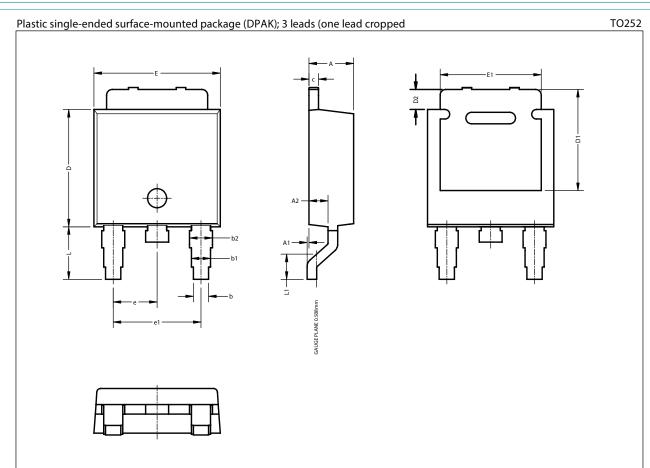
(2) $T_j = 100 \,^{\circ}\text{C}$; typical values

(3) $T_j = 125$ °C; typical values (4) $T_j = 150$ °C; typical values

Reverse leakage current as a function of reverse voltage; per diode; typical values



11. Package outline



Note:

1. All dimensions do not include mold flash & gate remain and metal protrusion.

Unit	Α	A 1	A2	b	b1	b2	С	D	D1	D2	Е	E1	е	e1	L	L1
min mm nom		0.00	0.90	0.70	0.86	1.06	0.46	5.97	5.05	0.98	6.45	5.20	2.30	4.60	2.60	1.25
		0.10	1.10	0.90	1.11	1.32	0.58	6.22	5.35	1.18	6.75	5.40	2.00		2.90	1.65

12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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